

## 1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT428 (DPAK) surface mountable plastic package intended for use in applications requiring sensitive gate, high bidirectional blocking voltage capability, high surge current capability and high thermal cycling performance.

## 2. Features and benefits

- High bidirectional blocking voltage capability
- High surge current capability
- High thermal cycling performance
- Sensitive gate
- Surface mountable package

## 3. Applications

- Ignition circuits
- Motor control
- Protection circuits
- Voltage regulation

## 4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DRM</sub>	repetitive peak off- state voltage		-	-	650	V
V <sub>RRM</sub>	repetitive peak reverse voltage		-	-	650	V
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 10 ms; <u>Fig. 4; Fig. 5</u>	-	-	120	A
		half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 8.3 ms	-	-	132	A
Tj	junction temperature		-	-	125	°C
I <sub>T(AV)</sub>	average on-state current	half sine wave; $T_{mb} \le 103 \text{ °C}$ ; Fig. 1	-	-	7.5	A
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 103 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	-	12	A
Static chara	octeristics					
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	2	5	mA
Dynamic ch	arateristics	· · · · ·				

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 436 V; T <sub>j</sub> = 125 °C; R <sub>GK</sub> = 100 Ω; exponential waveform; Fig. 13	200	1000	-	V/µs

# 5. Pinning information

Table 2. F	Pinning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode		А <del>- Д -</del> К
2	А	anode		G sym037
3	G	gate		Symoor
mb	A	mounting base; connected to anode	DPAK (SOT428)	

# 6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
BT151S-650L	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428				

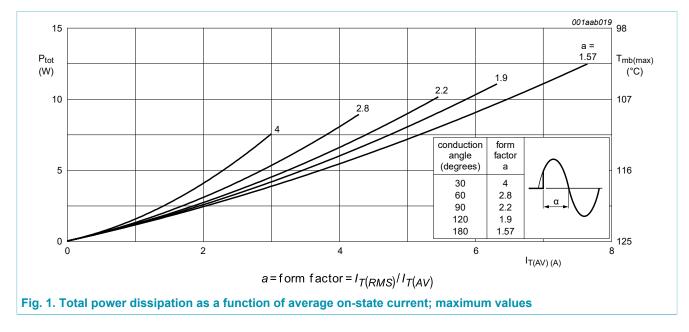


## 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	650	V
V <sub>RRM</sub>	repetitive peak reverse voltage		-	650	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>mb</sub> ≤ 103 °C; <u>Fig. 1</u>	-	7.5	А
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 103 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	12	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5	-	120	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	-	132	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN	-	72	A²s
dl <sub>T</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 10 mA	-	50	A/µs
I <sub>GM</sub>	peak gate current		-	2	А
V <sub>RGM</sub>	peak reverse gate voltage		-	5	V
P <sub>GM</sub>	peak gate power		-	5	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C



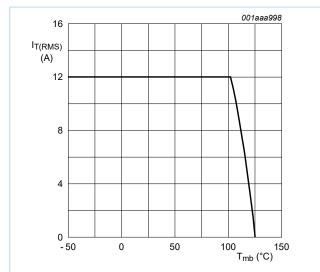
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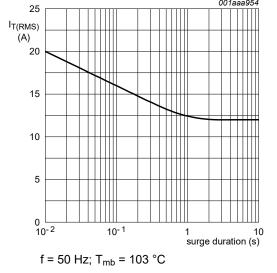
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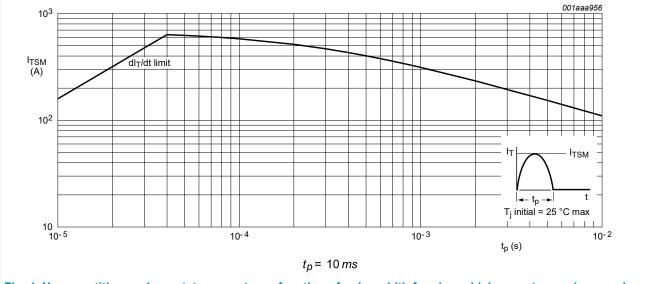
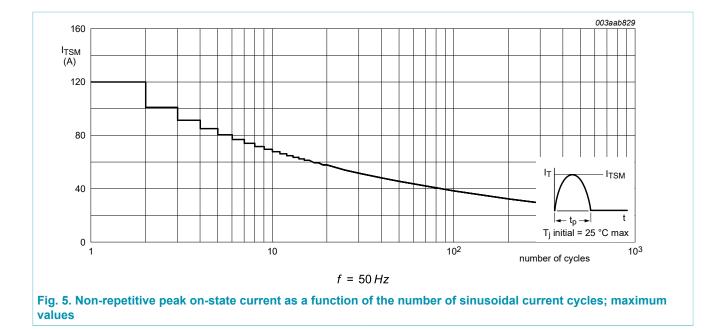


Fig. 4. Non-repetitive peak on-state current as a function of pulse width for sinusoidal currents; maximum values

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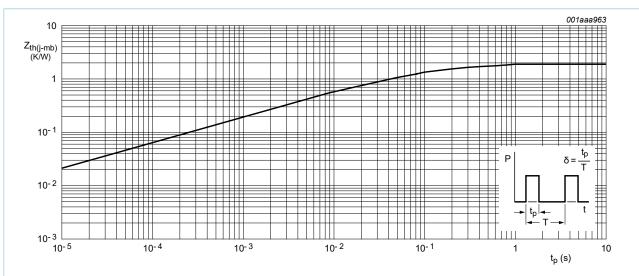


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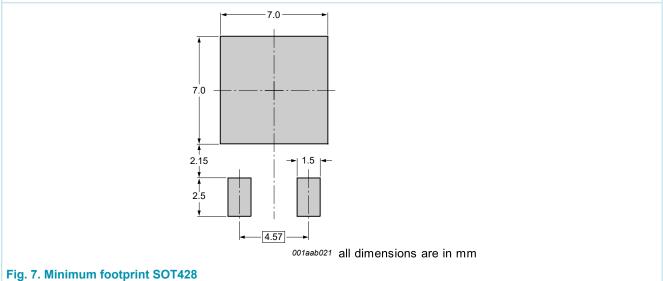


### 8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. <u>6</u>	-	-	1.8	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	mounted on an FR4 printed-circuit board; <u>Fig. 7</u>	-	75	-	K/W

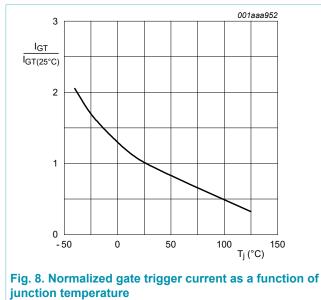


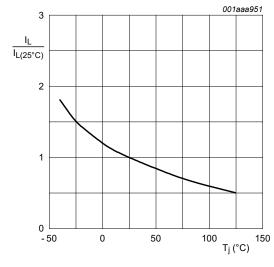
#### Fig. 6. Transient thermal impedance from junction to mounting base as as function of pulse width



### 9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics				,	
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	2	5	mA
۱ <sub>L</sub>	latching current	V <sub>D</sub> = 12 V; I <sub>G</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	10	40	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	7	20	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 23 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	1.4	1.75	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 12	-	0.6	1.5	V
		$V_D$ = 650 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C; Fig. 12	0.25	0.4	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 650 V; T <sub>j</sub> = 125 °C	-	0.1	0.5	mA
I <sub>R</sub>	reverse current	V <sub>R</sub> = 650 V; T <sub>j</sub> = 125 °C	-	0.1	0.5	mA
Dynamic ch	narateristics		· ·			
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 436 V; T <sub>j</sub> = 125 °C; R <sub>GK</sub> = 100 Ω; exponential waveform; Fig. 13	200	1000	-	V/µs
		$V_{DM}$ = 436 V; T <sub>j</sub> = 125 °C; exponential waveform; gate open circuit; Fig. 13	50	130	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM}$ = 40 A; V <sub>D</sub> = 650 V; I <sub>G</sub> = 0.1 A; dI <sub>G</sub> / dt = 5 A/µs; T <sub>j</sub> = 25 °C	-	2	-	μs
t <sub>q</sub>	commutated turn-off time		-	70	-	μs



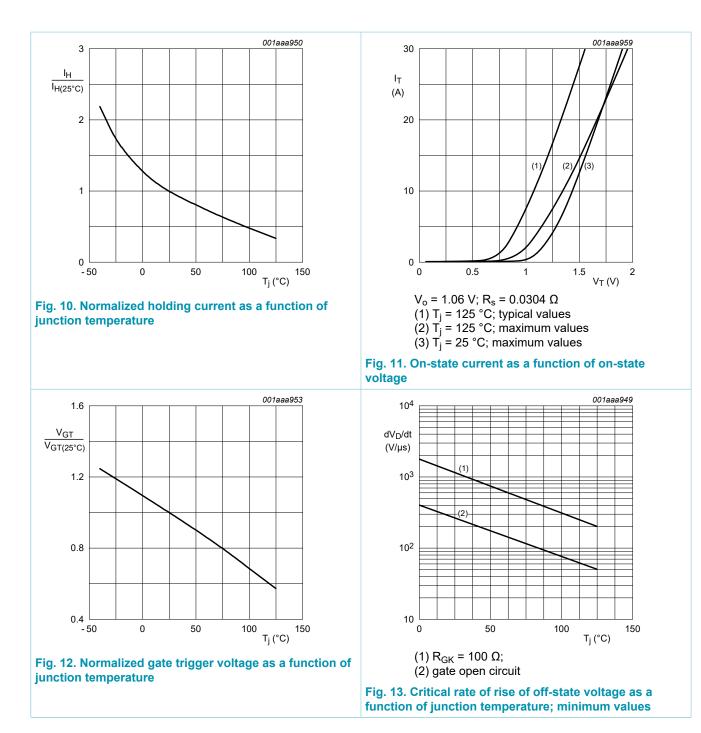


of Fig. 9. Normalized latching current as a function of junction temperature

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### **10.** Package outline

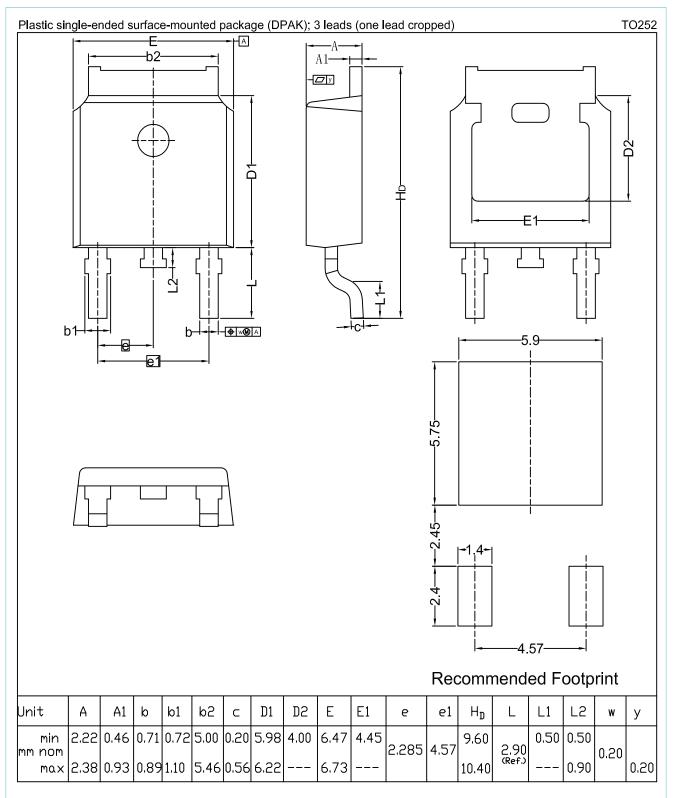


Fig. 14. Package outline DPAK (SOT428)

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## 11. Legal information

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Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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